

RBV2500 - RBV2510

PRV : 50 - 1000 Volts

Io : 25 Amperes

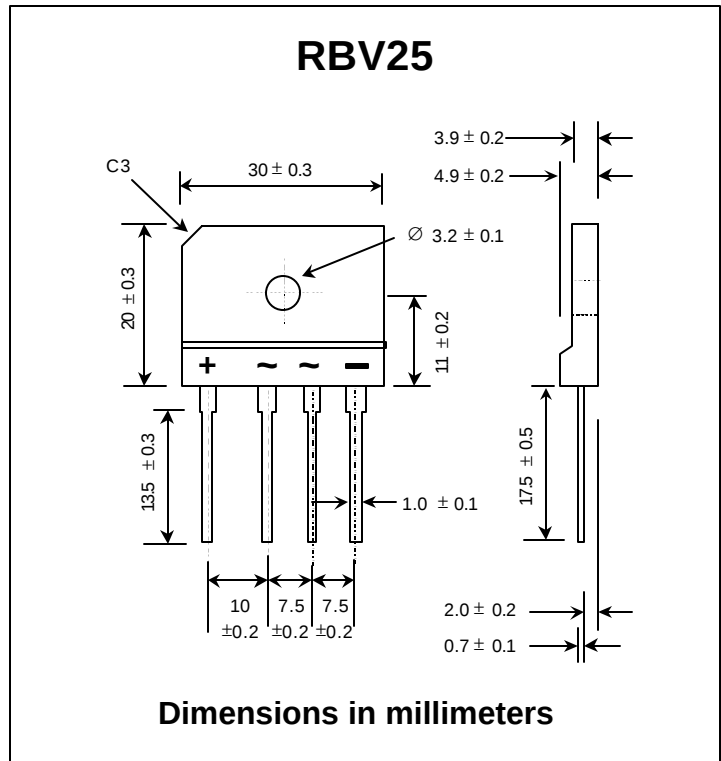
FEATURES :

- * High current capability
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * High case dielectric strength of 2000 V_{DC}
- * Ideal for printed circuit board
- * Very good heat dissipation

MECHANICAL DATA :

- * Case : Reliable low cost construction utilizing molded plastic technique
- * Epoxy : UL94V-O rate flame retardant
- * Terminals : Plated lead solderable per MIL-STD-202, Method 208 guaranteed
- * Polarity : Polarity symbols marked on case
- * Mounting position : Any
- * Weight : 7.7 grams

SILICON BRIDGE RECTIFIERS



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

RATING	SYMBOL	RBV 2500	RBV 2501	RBV 2502	RBV 2504	RBV 2506	RBV 2508	RBV 2510	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Current T _c = 55 °C	I _{F(AV)}	25							Amps.
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I _{FSM}	300							Amps.
Current Squared Time at t < 8.3 ms.	I ² _t	375							A ² S
Maximum Forward Voltage per Diode at I _F = 12.5 Amps.	V _F	1.1							Volts
Maximum DC Reverse Current Ta = 25 °C	I _R	10							μA
at Rated DC Blocking Voltage Ta = 100 °C	I _{R(H)}	200							μA
Typical Thermal Resistance (Note 1)	R _{θJC}	1.45							°C/W
Operating Junction Temperature Range	T _J	- 40 to + 150							°C
Storage Temperature Range	T _{STG}	- 40 to + 150							°C

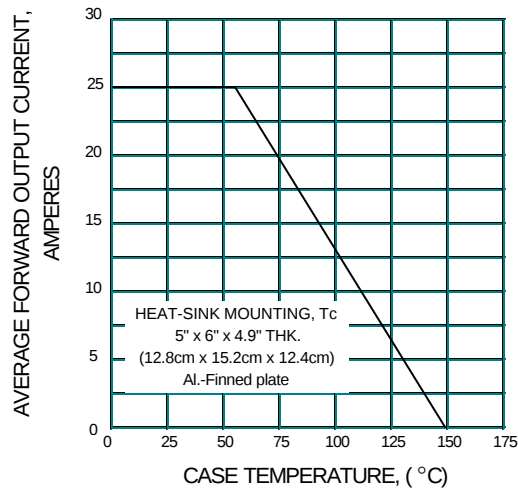
Notes :

1. Thermal resistance from junction to case with units mounted on a 5" x 6" x 4.9" (12.8cm.x 15.2cm.x 12.4cm.) Al.-Finned Plate

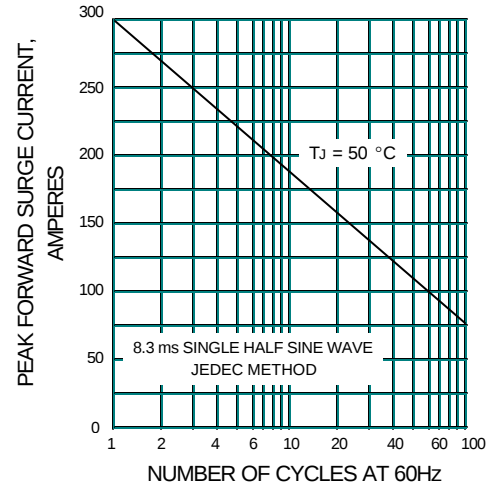
UPDATE : NOVEMBER 1,1998

RATING AND CHARACTERISTIC CURVES (RBV2500 - RBV2510)

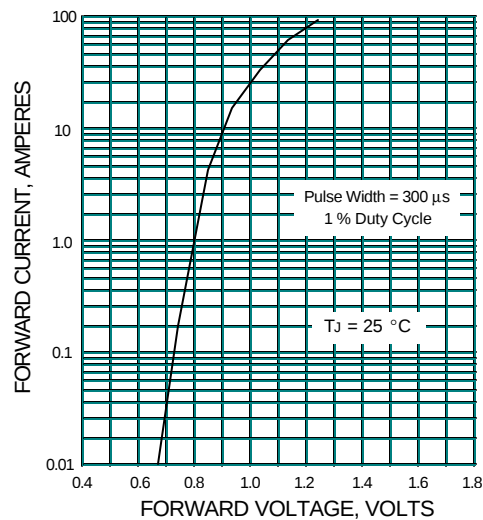
**FIG.1 - DERATING CURVE FOR OUTPUT
RECTIFIED CURRENT**



**FIG.2 - MAXIMUM NON-REPETITIVE PEAK
FORWARD SURGE CURRENT**



**FIG.3 - TYPICAL FORWARD CHARACTERISTICS
PER DIODE**



**FIG.4 - TYPICAL REVERSE CHARACTERISTICS
PER DIODE**

